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View Online at https://aerobasegroup.com/nsn/5962-01-135-5489

Body Length:

Between 1.180 inches and 1.220 inches

Body Width:

Between 0.560 inches and 0.600 inches

Body Height:

Between 0.080 inches and 0.130 inches

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-55.0/+70.0 degrees celsius

Storage Tempurature Range:

-65.0/+125.0 degrees celsius

End Application:

4920-01-054-8585 81755

Features Provided:

Hermetically sealed and monolithic and programmable

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Metal oxide-semiconductor logic

Input Circuit Pattern:

8 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-20.0 volts power source

Time Rating Per Chacteristic:

1000.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Rom

Test Data Document:

16340-64-00009 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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